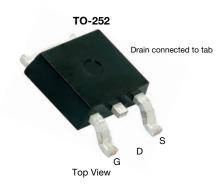


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Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET

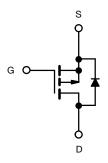


PRODUCT SUMMARY				
V _{DS} (V)	-40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0085			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0105			
I _D (A)	-50			
Configuration	Single			
Package	TO-252			

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % Rg and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	$T_C = 25 ^{\circ}C$, unles	s otherwise noted		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	-40	V
Gate-source voltage		V_{GS}	± 20	V
Continuous drain current ^a	T _C = 25 °C		-50	
Continuous drain current "	T _C = 125 °C	- I _D	-38	
Continuous source current (diode conduction	I _S	-50	Α	
Pulsed drain current ^b		I _{DM}	-200	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-35	
Single pulse avalanche energy	L = U.1 IIII	E _{AS}	61	mJ
Maximum power dissipation ^b	T _C = 25 °C	P _D	71	W
	T _C = 125 °C		23	VV
Operating junction and storage temperature r	ange	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient PC	CB mount c	R_{thJA}	50	°C/W
Junction-to-case (drain)		R _{thJC}	2.1	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-40	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$		-2.0	-2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -40 V, T _J = 125 °C	-	-	-50	μΑ
		$V_{GS} = 0 V$	V _{DS} = -40 V, T _J = 175 °C	-	-	-200	
On-state drain current a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 \text{ V}$	-50	-	-	Α
		V _{GS} = -10 V	I _D = -25 A	-	0.0070	0.0085	
Drain-source on-state resistance ^a		V _{GS} = -10 V	I _D = -25 A, T _J = 125 °C	-	-	0.0110	Ω 1 5 S
	R _{DS(on)}	V _{GS} = -10 V	I _D = -25 A, T _J = 175 °C	-	-	0.0131	
		V _{GS} = -4.5 V	I _D = -20 A	-	0.0086	0.0105	
Forward transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -25 A	-	92	-	S
Dynamic ^b					•		•
Input capacitance	C _{iss}			-	7365	9950	
Output capacitance	C _{oss}	V _{GS} = 0 V	V _{DS} = -25 V, f = 1 MHz	-	576	800	рF
Reverse transfer capacitance	C _{rss}			-	548	750	
Total gate charge ^c	Q_{g}			-	138	210	
Gate-source charge c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -20 \text{ V}, I_{D} = -50 \text{ A}$	-	21	-	nC
Gate-drain charge ^c	Q _{gd}			-	21	-	
Gate resistance	R _g		f = 1 MHz	1.5	3.15	4.8	Ω
Turn-on delay time c	t _{d(on)}			-	13	20	
Rise time ^c	t _r	V _{DD} =	-20 V, R_L = 0.4 Ω	-	81	130	
Turn-off delay time ^c	t _{d(off)}	I _D ≅ -50 A,	$I_D \cong -50 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		103	160	ns
Fall time ^c	t _f			-	153	250	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	-200	Α
Forward voltage	V_{SD}	I _F =	-50 A, V _{GS} = 0 V	-	-0.96	-1.5	V
Body diode reverse recovery time	t _{rr}			-	56	120	ns
Body diode reverse recovery charge	Q _{rr}	1 00	A di/dt 100 A/vo	-	83	170	nC
Reverse recovery fall time	t _a	I _F = -30	A, di/dt = 100 A/μs	-	34	-	
Reverse recovery rise time	t _b			-	22	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.8	-	Α

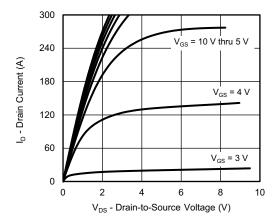
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

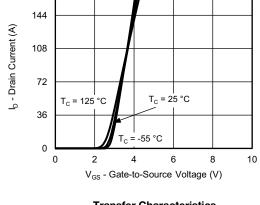
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

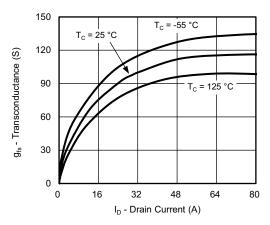


Output Characteristics

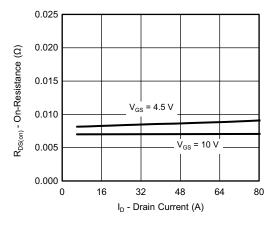


180

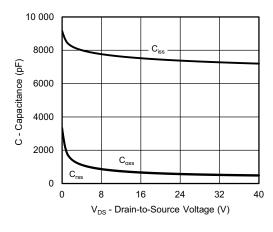
Transfer Characteristics



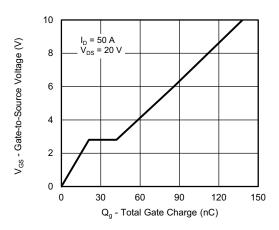
Transconductance



On-Resistance vs. Drain Current



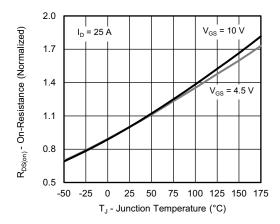




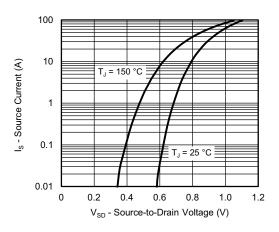
Gate Charge



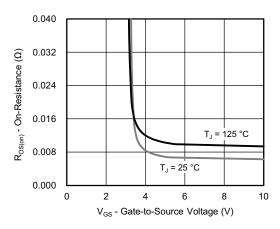
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



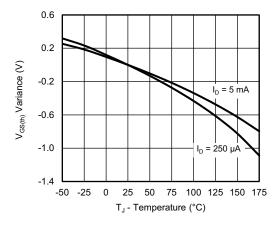
On-Resistance vs. Junction Temperature



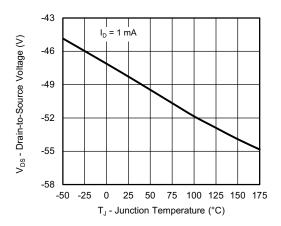
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



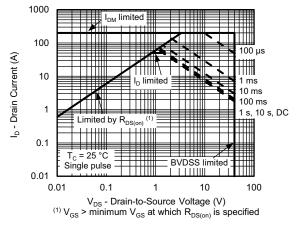
Threshold Voltage



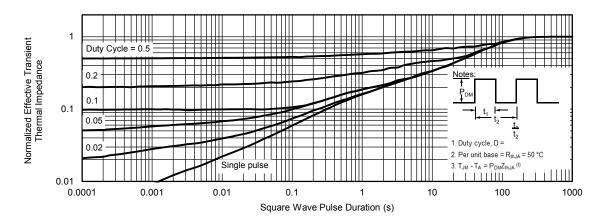
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



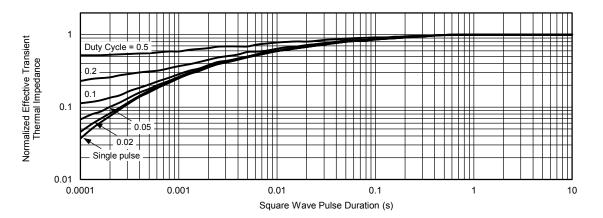
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

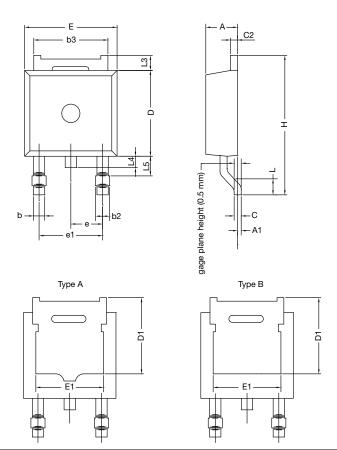
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg275677.



TO-252AA Case Outline



DIM.	MILLIN	METERS	INCHES	
	MIN.	MAX.	MIN.	MAX.
Α	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
С	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	=
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	=
Н	9.40	10.41	0.370	0.410
е	2.28	BSC	0.090	BSC
e1	4.56 BSC		0.180	BSC
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060

ECN: T25-0122-Rev. C, 12-May-2025 DWG: 6019

Notes

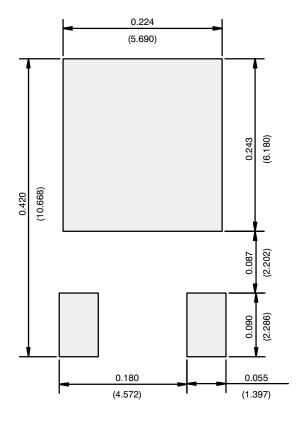
• Dimension L3 is for reference only

Dimension D1 and E1 on type A and B is the same

Revision: 12-May-2025 1 Document Number: 64424



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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